

Description

The AP2501A and AP2511A are single channel current-limited integrated high-side power switches optimized for Universal Serial Bus (USB) and other hot-swap applications. The family of devices complies with USB standards and is available with both polarities of Enable input.

The devices have fast short-circuit response time for improved overall system robustness, and include integrated output discharge function to ensure completely controlled discharging of the output voltage capacitor. They provide a complete protection solution for applications subject to heavy capacitive loads and the prospect of short circuit, and offer reverse current blocking, over-current, over-temperature and short-circuit protection, as well as controlled rise time and under-voltage lockout functionality. A 7ms deglitch capability on the open-drain Flag output prevents false overcurrent reporting and does not require any external components.

All devices are available in SO-8, MSOP-8, MSOP-8EP, U-DFN3030-8 and U-DFN2020-6 packages.

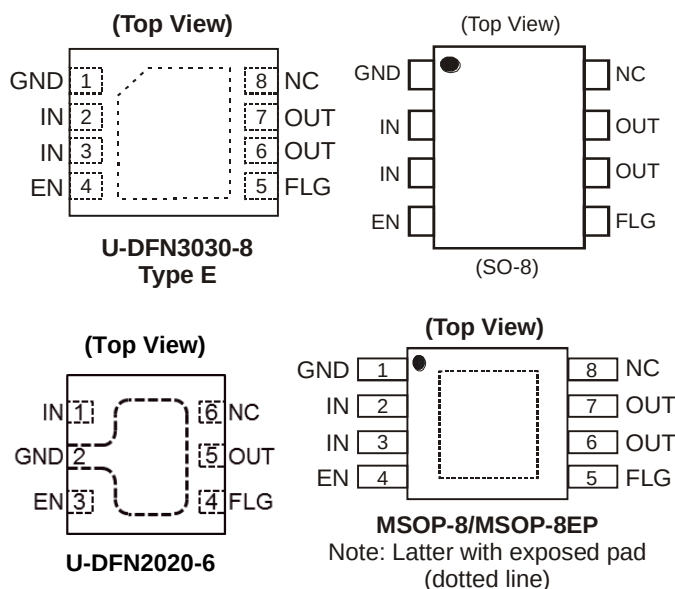
Features

- Single channel current-limited power switch
- Output discharge function
- Fast short-circuit response time: 2μs
- 3.7A accurate current limiting (typ)
- Reverse current blocking
- 70mΩ on-resistance (typ)
- Input voltage range: 2.7V – 5.5V
- Built-in soft-start with 0.6ms typical rise time
- Overcurrent and thermal protection
- Fault report (FLG) with blanking time (7ms typ)
- ESD protection: 2KV HBM, 200V MM
- Active low (AP2501A) or active high (AP2511A) enable
- Ambient temperature range: -40°C to +85°C
- SO-8, MSOP-8, MSOP-8EP, U-DFN3030-8 and U-DFN2020-6:
Available in "Green" Molding Compound (No Br, Sb)
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- UL Recognized, File Number E322375
- IEC60950-1 CB Scheme Certified
- Moisture Sensitivity: Level 1 per J-STD-020

Notes:

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

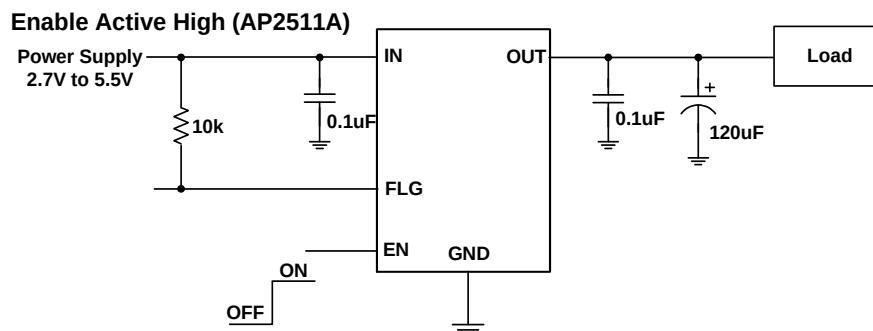
Pin Assignments



Applications

- LCD TVs & Monitors
- Set-Top-Boxes, Residential Gateways
- Laptops, Desktops, Servers, E-Readers
- Printers, Docking Stations, HUBs

Typical Applications Circuit



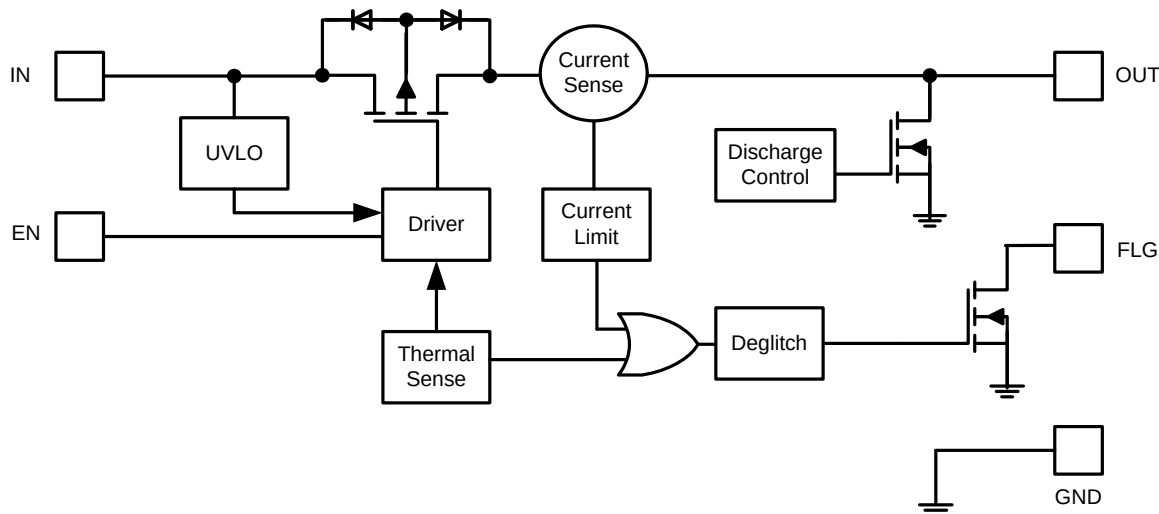
Available Options

Part Number	Channel	Enable Pin (EN)	Recommended Maximum Continuous Load Current (A)	Typical Current Limit (A)	Package
AP2501A	1	Active Low	2.5A	3.7A	SO-8 MSOP-8 MSOP-8EP U-DFN3030-8 U-DFN2020-6
AP2511A	1	Active High			

Pin Descriptions

Pin Name	Pin Number			Function
	MSOP-8EP, U-DFN3030-8	SO-8, MSOP-8	U-DFN2020-6	
GND	1	1	2	Ground
IN	2, 3	2, 3	1	Voltage Input Pin. Connect a 0.1μF or larger ceramic capacitor from IN to GND as close as possible. (all IN pins must be tied together externally)
EN	4	4	3	Enable Input. Active low (AP2501A) or active high (AP2511A).
FLG	5	5	4	Over-temperature and over-current fault reporting with 7ms deglitch; active low open-drain output. FLG is disabled for 7ms after turn-on.
OUT	6, 7	6, 7	5	Voltage Output Pin (all OUT pins must be tied together externally)
NC	8	8	6	No internal connection; recommend tie to OUT pins.
Exposed Pad	Exposed Pad	Not applicable	Exposed Pad	Exposed pad. It should be externally connected to GND and thermal mass for enhanced thermal impedance. It should not be used as electrical ground conduction path.

Functional Block Diagram



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD MM	Machine Model ESD Protection	200	V
V _{IN}	Input Voltage (Note 4)	-0.3 to +6.5	V
V _{OUT}	Output Voltage (Note 4)	-0.3 to V _{IN} +0.3 or 6.5	V
V _{EN} , V _{FLG}	Enable Voltage (Note 4)	-0.3 to V _{IN} +0.3 or 6.5	V
I _{LOAD}	Maximum Continuous Load Current	Internal Limited	A
T _{JMAX}	Maximum Junction Temperature	+150	°C
T _{ST}	Storage Temperature Range (Note 5)	-65 to +150	°C

Notes: 4. All voltages referred to GND pin. Maximums are the lower of (V_{IN} + 0.3V) and 6.5V.
5. UL Recognized Rating from -30°C to +70°C (Diodes qualified T_{ST} from -65°C to +150°C).

Caution: Stresses greater than the 'Absolute Maximum Ratings' specified above, may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

Semiconductor devices are ESD sensitive and may be damaged by exposure to ESD events. Suitable ESD precautions should be taken when handling and transporting these devices

Recommended Operating Conditions (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
V _{IN}	Input Voltage	2.7	5.5	V
I _{OUT}	Output Current	0	2.5	A
V _{IH}	High-Level Input Voltage on EN	2.0	V _{IN}	V
V _{IL}	Low-Level Input Voltage on EN	0	0.8	V
T _A	Operating Ambient Temperature (Note 6)	-40	+85	°C

Note: 6. T_{A(MAX)} = +70°C if V_{IN} ≤ 4.1V and I_{OUT} = 2.5A to keep device from going into thermal protection.

Electrical Characteristics (@ T_A = +25°C, V_{IN} = +5.0V, C_{IN} = 0.1μF, C_L = 1μF, unless otherwise specified.)

Symbol	Parameter	Conditions (Note 7)		Min	Typ	Max	Unit
V _{UVLO}	Input UVLO	V _{IN} rising		1.6	2.0	2.4	V
ΔV _{UVLO}	Input UVLO Hysteresis	V _{IN} decreasing		-	50		mV
I _{SHDN}	Input Shutdown Current	Disabled, OUT = open		-	0.1	1.0	μA
I _Q	Input Quiescent Current	Enabled, OUT = open		-	60	100	μA
I _{LEAK}	Input Leakage Current	Disabled, OUT grounded		-	0.1	1.0	μA
I _{REV}	Reverse Leakage Current	Disabled, V _{IN} = 0V, V _{OUT} = 5V, I _{REV} at V _{IN}		-	0.01	1.00	μA
R _{DS(ON)}	Switch on-Resistance	V _{IN} = 5V, I _{OUT} = 1A	T _A = 25°C	-	70	78	mΩ
			-40°C ≤ T _A ≤ +85°C	-	-	105	
		V _{IN} = 3.3V, I _{OUT} = 1A	T _A = 25°C	-	90	108	
			-40°C ≤ T _A ≤ +85°C	-	-	135	
I _{LIMIT}	Overload Current Limit (Note 7)	V _{IN} = 5V, V _{OUT} = 4.5V	-40°C ≤ T _A ≤ +85°C	2.8	3.7	4.6	A
I _{TRIG}	Current Limiting Trigger Threshold	Output Current Slew rate (<100A/s)		-	3.7	-	A
I _{SHORT}	Short-Circuit Current Limit	Enabled into short circuit		-	3.7	-	A
T _{SHORT}	Short-Circuit Response Time	V _{OUT} = 0V to I _{OUT} = I _{LIMIT} (OUT shorted to ground)		-	2	-	μs
V _{IL}	EN Input Logic Low Voltage	V _{IN} = 2.7V to 5.5V		-	-	0.8	V
V _{IH}	EN Input Logic High Voltage	V _{IN} = 2.7V to 5.5V		2	-	-	V
I _{LEAK-EN}	EN Input Leakage	V _{IN} = 5V, V _{EN} = 0V and 5.5V		-	0.01	1.00	μA
I _{LEAK-O}	Output Leakage Current	Disabled, V _{OUT} = 0V		-	0.5	1	μA
T _{D(ON)}	Output turn-on Delay Time	C _L = 1μF, R _{LOAD} = 5Ω		-	0.1	-	ms
T _R	Output turn-on Rise Time	C _L = 1μF, R _{LOAD} = 5Ω		-	0.6	1.5	ms
T _{D(OFF)}	Output turn-off Delay Time	C _L = 1μF, R _{LOAD} = 5Ω		-	0.1		ms
T _F	Output turn-off Fall Time	C _L = 1μF, R _{LOAD} = 5Ω		-	0.05	0.10	ms
R _{FLG}	FLG output FET on-Resistance	I _{FLG} = 10mA		-	20	40	Ω
I _{FOH}	FLG Off Current	V _{FLG} = 5V		-	0.01	1.00	μA
T _{BLANK}	FLG Blanking Time	Assertion or deassertion due to overcurrent and over-temperature condition		4	7	15	ms
T _{DIS}	Discharge Time	C _L = 1μF, V _{IN} = 5V, disabled to V _{OUT} < 0.5V		-	0.6	-	ms
R _{DIS}	Discharge Resistance (Note 8)	V _{IN} = 5V, disabled, I _{OUT} = 1mA		-	105	-	Ω
T _{SHDN}	Thermal Shutdown Threshold	Enabled		-	+140	-	°C
T _{HYS}	Thermal Shutdown Hysteresis	-		-	+20	-	°C
θ _{JA}	Thermal Resistance Junction-to-Ambient	SO-8 (Note 9)		-	96	-	°C/W
		MSOP-8 (Note 9)		-	130	-	°C/W
		MSOP-8EP (Note 10)		-	92	-	°C/W
		U-DFN3030-8 (Note 10)		-	84	-	°C/W
		U-DFN2020-6 (Note 11)		-	90	-	°C/W

- Notes:
- Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.
 - The discharge function is active when the device is disabled (when enable is de-asserted or during power-up power-down when V_{IN} < V_{UVLO}). The discharge function offers a resistive discharge path for the external storage capacitor for limited time.
 - Device mounted on 2" x 2" FR-4 substrate PCB, 2oz copper, with minimum recommended pad layout.
 - Device mounted on 2" x 2" FR-4 substrate PCB, 2oz copper, with minimum recommended pad on top layer and thermal vias to bottom layer ground plane.
 - Device mounted on 1" x 1" FR-4 substrate PCB, 2oz copper, with minimum recommended pad on top layer and thermal vias to bottom layer ground plane.

Typical Performance Characteristics

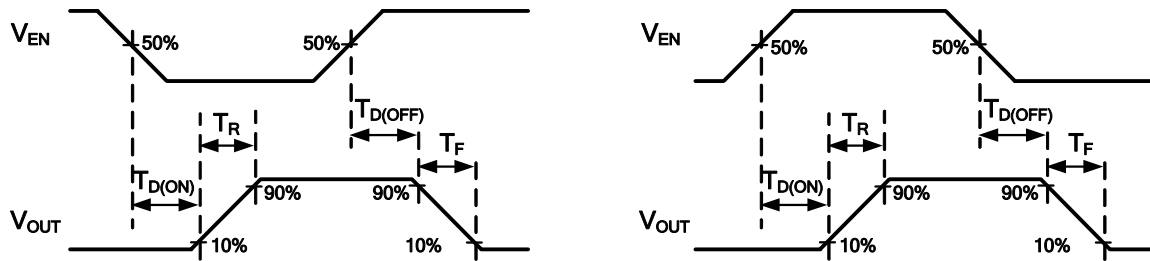
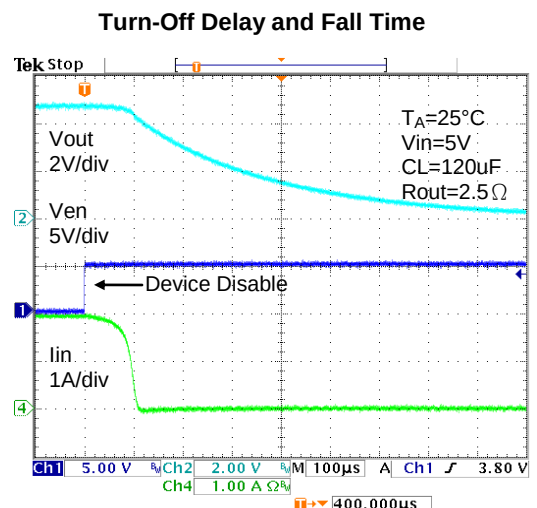
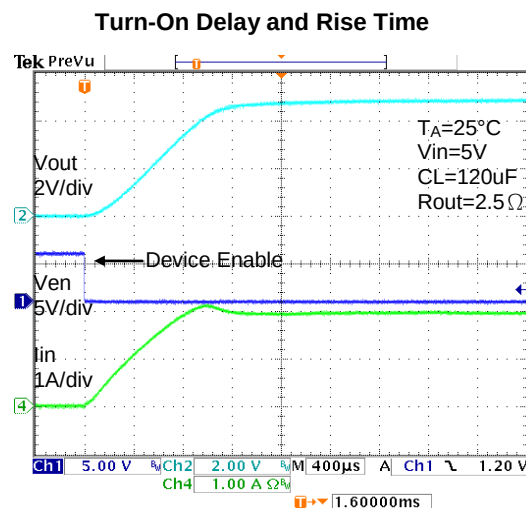
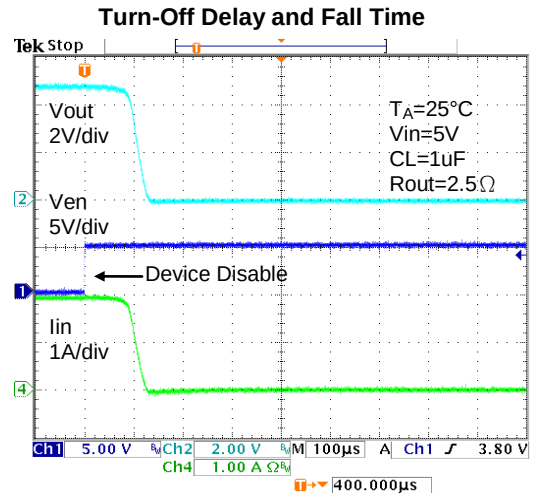
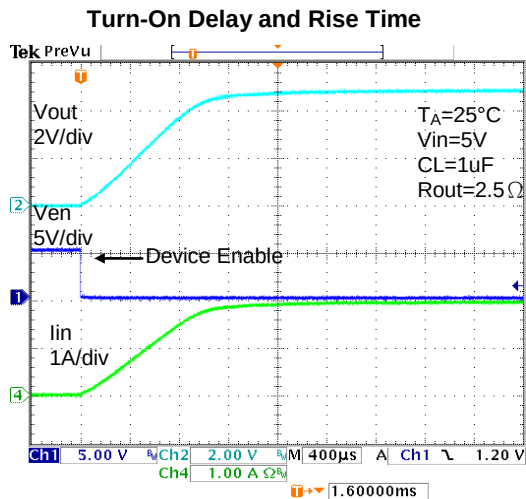


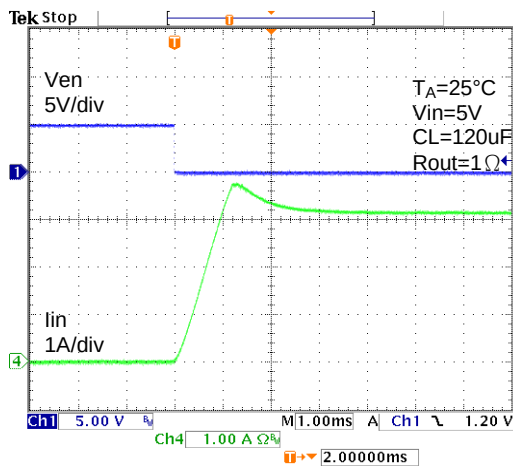
Figure 1 Voltage Waveforms: AP2501A (left), AP2511A (right)

All Enable Plots are for Enable Active Low

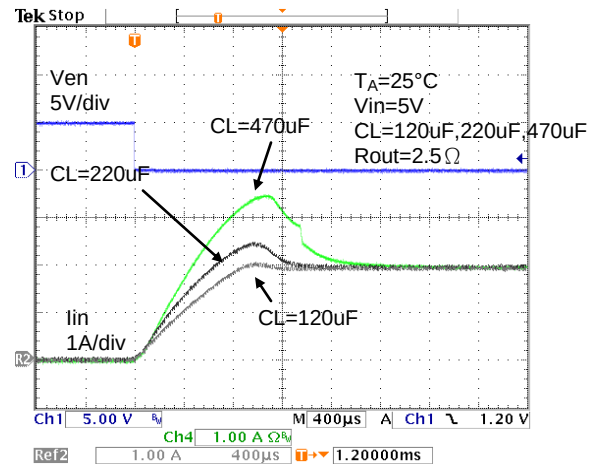


Typical Performance Characteristics (continued)

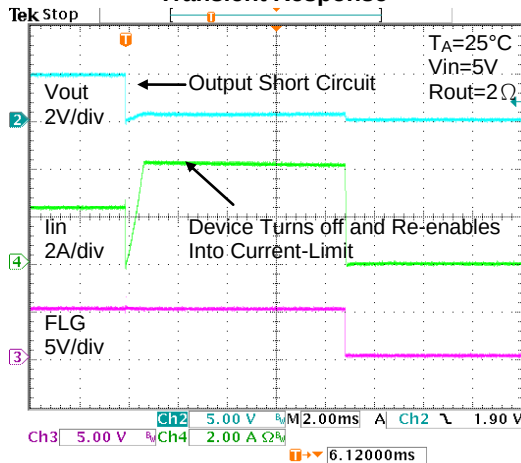
Device Enabled Into Short-Circuit



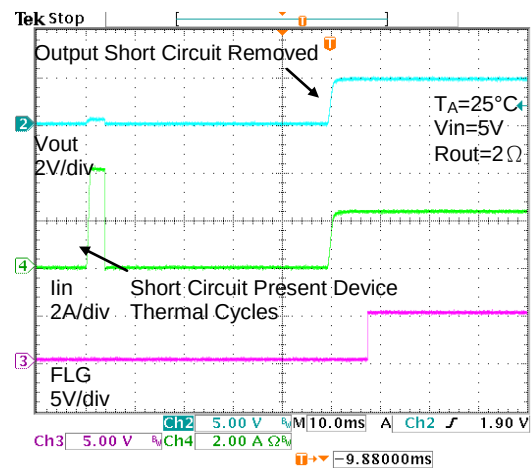
Inrush Current



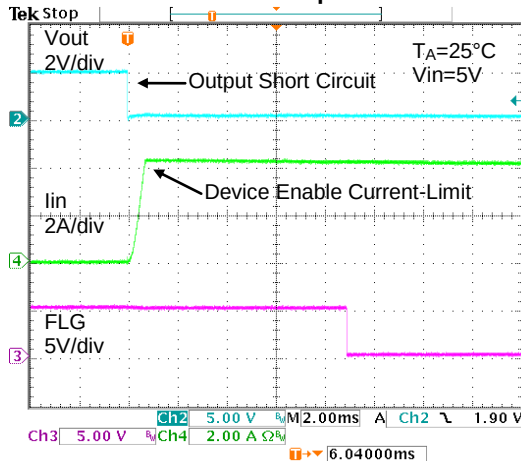
Full-Load to Short-Circuit Transient Response



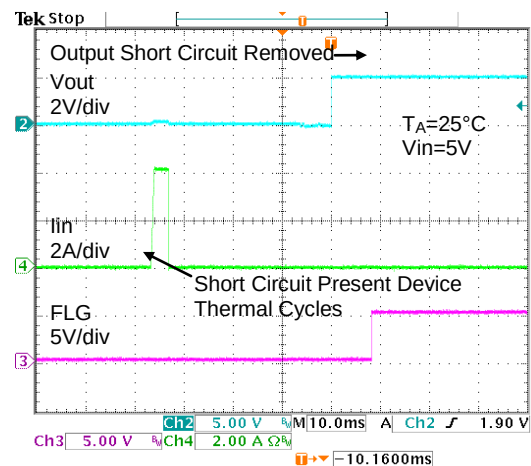
Short-Circuit to Full-Load Recovery Response



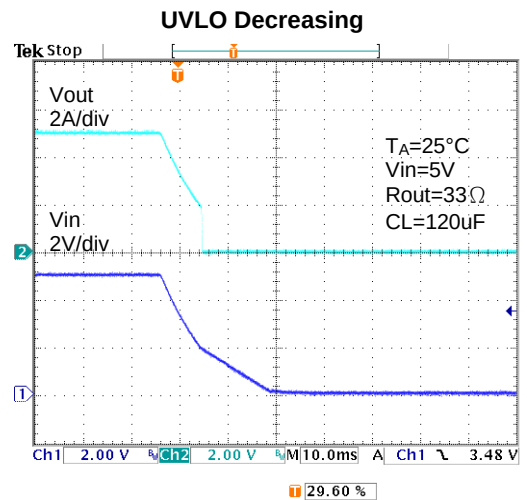
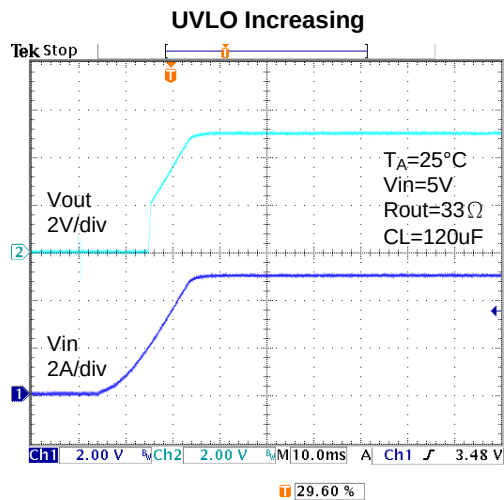
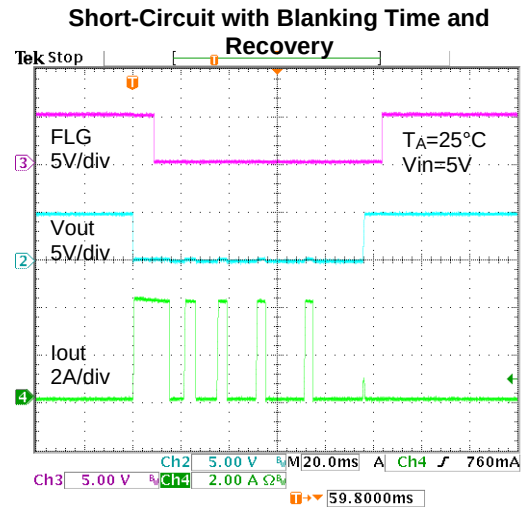
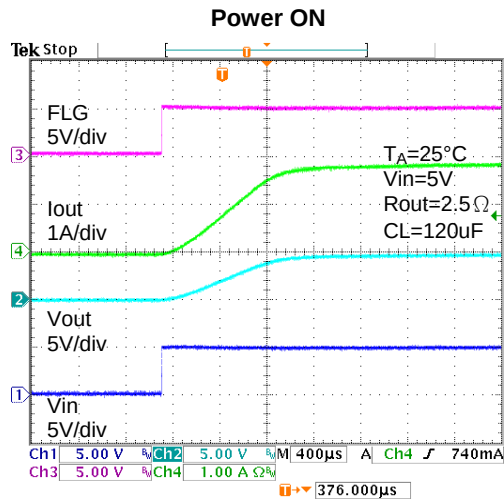
No-Load to Short-Circuit Transient Response



Short-Circuit to No-Load Recovery Response



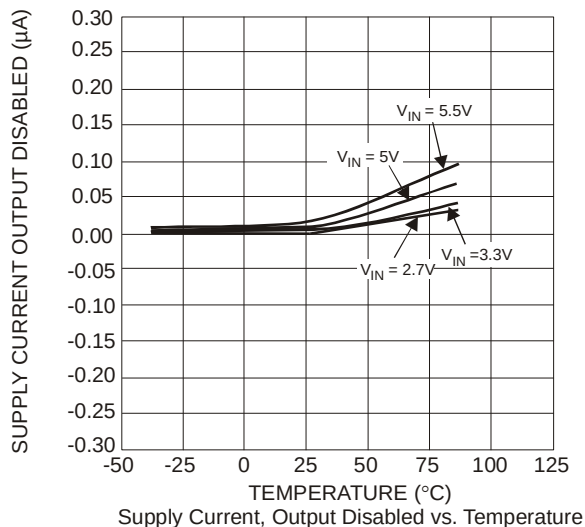
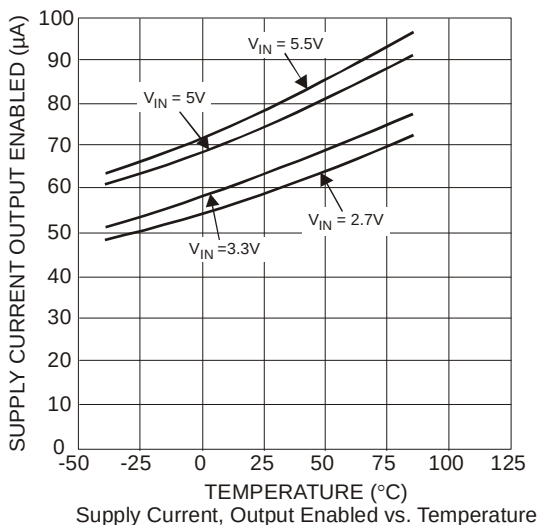
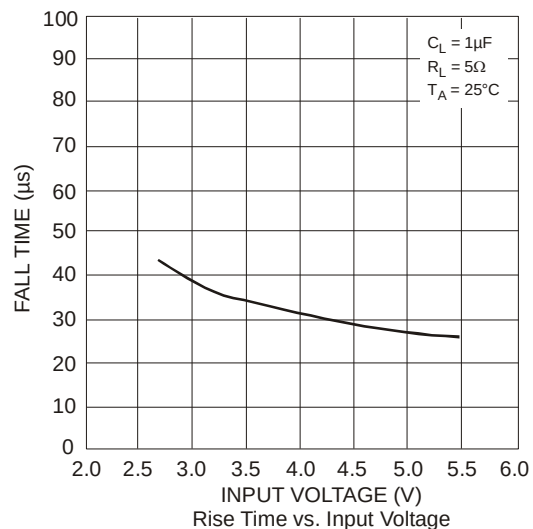
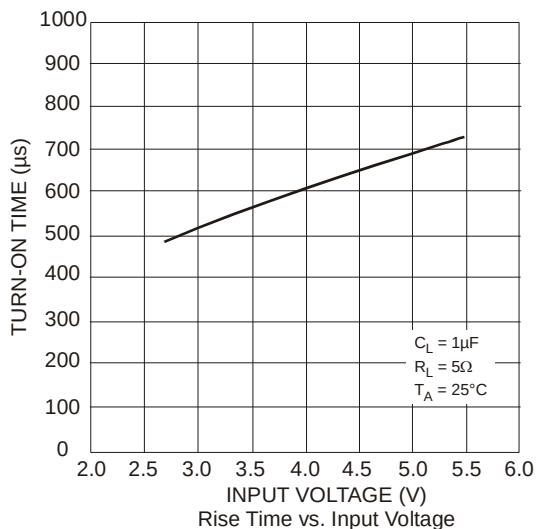
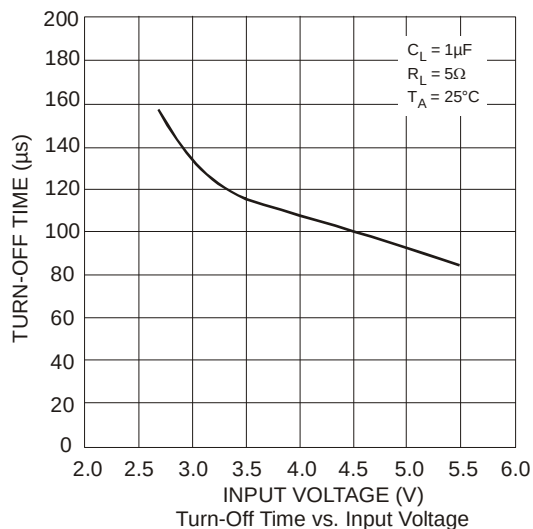
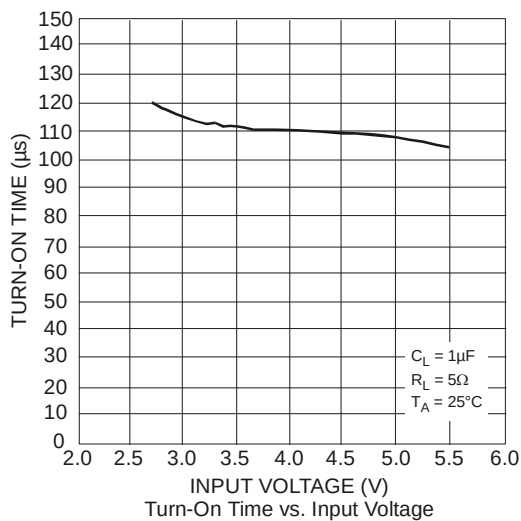
Typical Performance Characteristics (cont.)



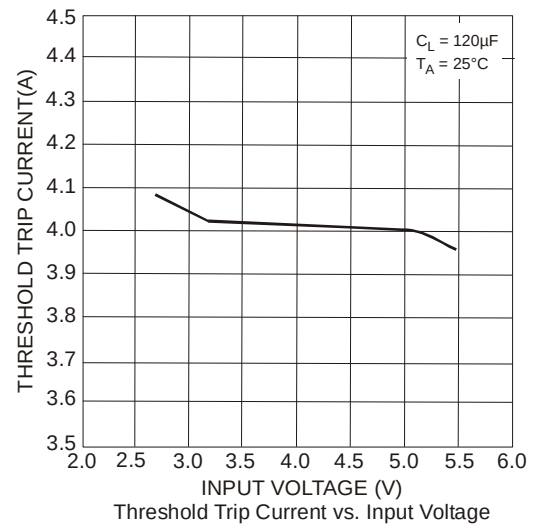
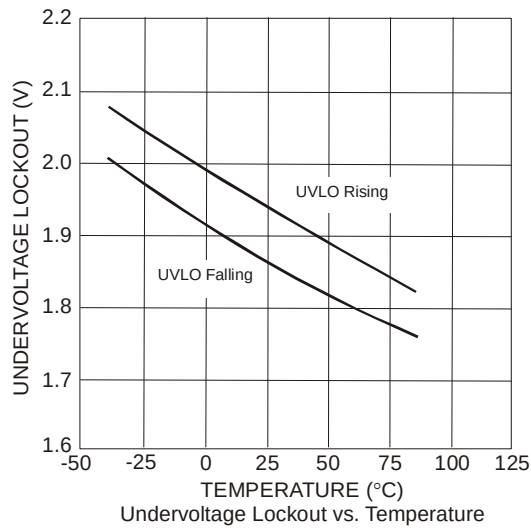
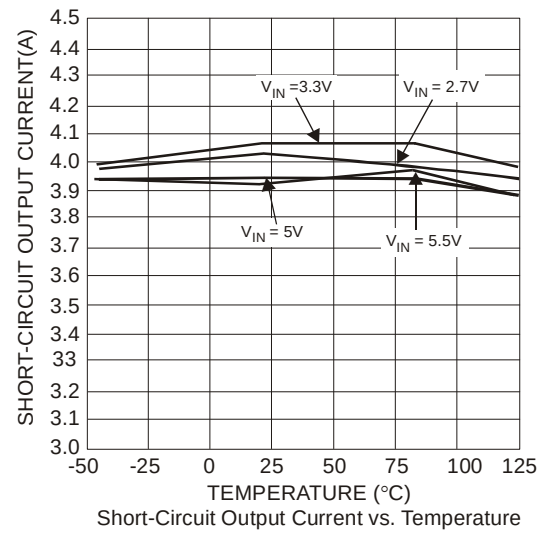
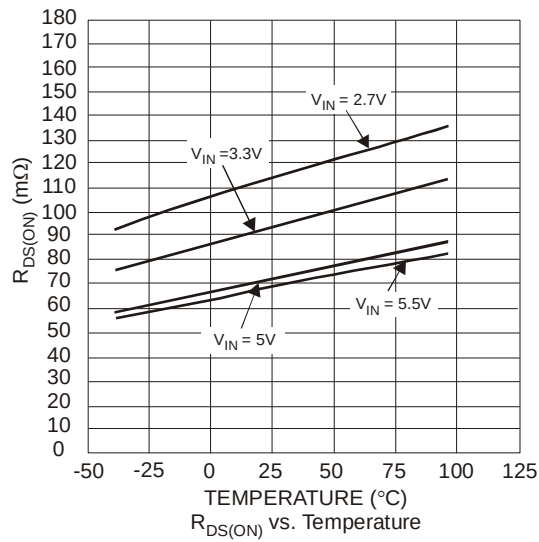
1 Dec 2011
17:16:50

1 Dec 2011
16:48:05

Typical Performance Characteristics (cont.)



Typical Performance Characteristics (cont.)



Application Note

Power Supply Considerations

A 0.1µF to 2.2µF X7R or X5R ceramic bypass capacitor placed between IN and GND, close to the device, is recommended. When an external power supply is used, or an additional ferrite bead is added to the input, high inrush current may cause voltage spikes higher than the device maximum input rating during short circuit condition. In this case a 2.2µF or bigger capacitor is recommended. Placing a high-value electrolytic capacitor on the input and output pin(s) is recommended when the output load is heavy. This precaution reduces power-supply transients that may cause ringing on the input. Additionally, bypassing the output with a 0.1µF to 1.0µF ceramic capacitor improves the immunity of the device to short circuit transients.

Overcurrent and Short Circuit Protection

An internal sensing FET is employed to check for overcurrent conditions. Unlike current-sense resistors, sense FETs do not increase the series resistance of the current path. When an overcurrent condition is detected, the device maintains a constant output current and reduces the output voltage accordingly. Complete shutdown occurs only if the fault stays long enough to activate thermal limiting.

Three possible overload conditions can occur. In the first condition, the output has been shorted to GND before the device is enabled or before VIN has been applied. The AP2501A/AP2511A senses the short circuit and immediately clamps output current to a certain safe level namely I_{SHORT} .

In the second condition, an output short or an overload occurs while the device is enabled. At the instance the overload occurs, higher inrush current may flow for a very short period of time before the current limit function can react. The input capacitor(s) rapidly discharge through the device, activating current limit circuitry. Protection is achieved by momentarily opening the P-MOS high-side power switch and then gradually turning it on. After the current limit function has tripped (reached the overcurrent trip threshold), the device switches into current limiting mode and the current is clamped at I_{LIMIT} .

In the third condition, the load has been gradually increased beyond the recommended operating current. The current is permitted to rise until the current-limit threshold (I_{TRIG}) is reached or until the thermal limit of the device is exceeded. The AP2501A/AP2511A is capable of delivering current up to the current-limit threshold without damaging the device. Once the threshold has been reached, the device switches into its current limiting mode and is set at I_{LIMIT} .

FLG Response

When an overcurrent or over-temperature shutdown condition is encountered, the FLG open-drain output goes active low after a nominal 7-ms deglitch timeout. The FLG output remains low until both overcurrent and over-temperature conditions are removed.

Connecting a heavy capacitive load to the output of the device can cause a momentary overcurrent condition, which does not trigger the FLG due to the 7-ms deglitch timeout. The AP2501A/AP2511A is designed to eliminate false overcurrent reporting without the need of external components to remove unwanted pulses.

Power Dissipation and Junction Temperature

The low on-resistance of the internal MOSFET allows the small surface-mount packages to pass large current. Using the maximum operating ambient temperature (T_A) and $R_{DS(ON)}$, the power dissipation can be calculated by:

$$P_D = R_{DS(ON)} \times I^2$$

Finally, calculate the junction temperature:

$$T_J = P_D \times R_{\theta JA} + T_A$$

Where:

T_A = Ambient temperature °C

$R_{\theta JA}$ = Thermal resistance

P_D = Total power dissipation

Thermal Protection

Thermal protection prevents the IC from damage when heavy-overload or short-circuit faults are present for extended periods of time. The AP2501A/AP2511A implements a thermal sensing to monitor the operating junction temperature of the power distribution switch. Once the die temperature rises to approximately 140°C due to excessive power dissipation in an overcurrent or short-circuit condition the internal thermal sense circuitry turns the power switch off, thus preventing the power switch from damage. Hysteresis is built into the thermal sense circuit allowing the device to cool down approximately 20°C before the switch turns back on. The switch continues to cycle in this manner until the load fault or input power is removed. The FLG open-drain output is asserted when an over-temperature shutdown or overcurrent occurs with 7-ms deglitch.

Application Note (continued)

Undervoltage Lockout (UVLO)

Undervoltage lockout function (UVLO) keeps the internal power switch from being turned on until the power supply has reached at least 2V, even if the switch is enabled. Whenever the input voltage falls below approximately 2V, the power switch is quickly turned off. This facilitates the design of hot-insertion systems where it is not possible to turn off the power switch before input power is removed.

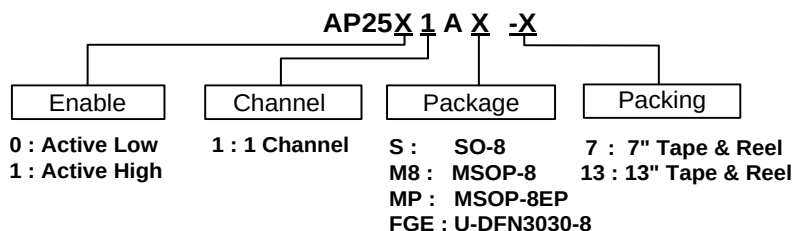
Discharge Function

The discharge function of the device is active when enable is disabled or de-asserted. The discharge function with the N-MOS power switch implementation is activated and offers a resistive discharge path for the external storage capacitor. This is designed for discharging any residue of the output voltage when either no external output resistance or load resistance is present at the output.

Dual-Purpose Port Applications

AP2501A/AP2511A requires special consideration for use in dual-purpose port applications in which a single port is used for data communication between the host and peripheral devices while simultaneously maintaining a charge to the battery of the peripheral device. An example of such application is a shared HDMI/MHL (Mobile High-definition Link) port that allows streaming video between an HDTV or set-top box and a smartphone or tablet while maintaining a charge to the smartphone or tablet battery. Since the AP2501A/AP2511A includes an embedded discharge feature that discharges the output load of the device when the device is disabled, the batteries of the connected peripheral device will be subject to continual discharge whenever the AP2501A/AP2511A is disabled. An overstress condition to the device's discharge MOS transistor may result. In addition, if the output of the AP2501A/AP2511A is subjected to a constant voltage that would be present during a dual-purpose port application such as MHL, an overstress condition to the device may result.

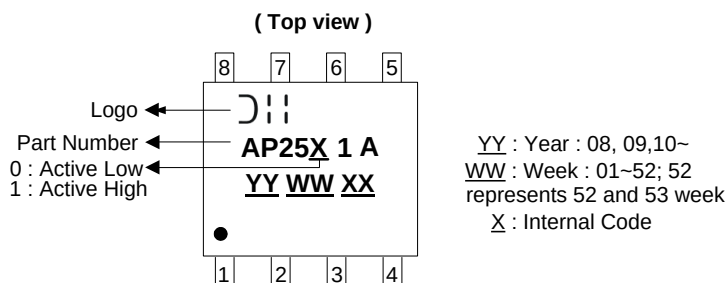
Ordering Information



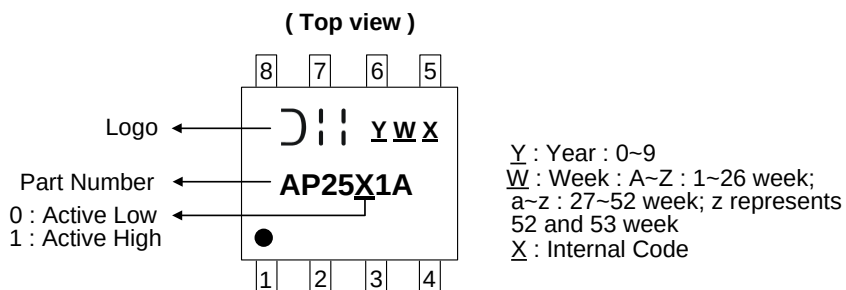
Part Number	Package Code	Packaging	7"/13" Tape and Reel	
			Quantity	Part Number Suffix
AP25X1AS-13	S	SO-8	2,500/Tape & Reel	-13
AP25X1AM8-13	M8	MSOP-8	2,500/Tape & Reel	-13
AP25X1AMP-13	MP	MSOP-8EP	2,500/Tape & Reel	-13
AP25X1AFGE-7	FGE	U-DFN3030-8	3,000/Tape & Reel	-7
AP25X1ASN-7	SN	U-DFN2020-6	3,000/Tape & Reel	-7

Marking Information

(1) SO-8

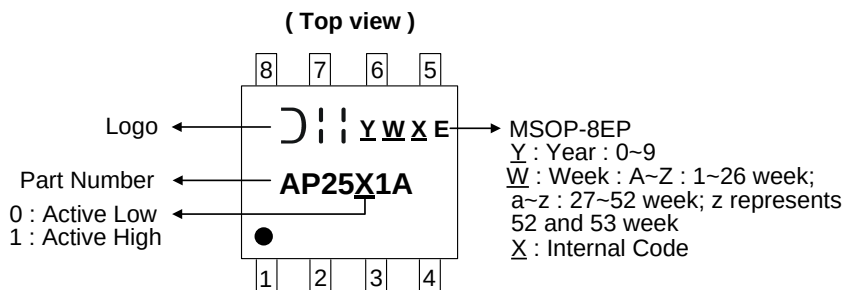


(2) MSOP-8



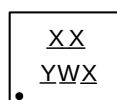
Marking Information (continued)

(3) MSOP-8EP



(4) U-DFN3030-8

(Top View)

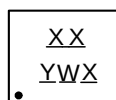


XX : Identification Code
Y : Year : 0~9
W : Week : A~Z : 1~26 week;
a~z : 27~52 week; z represents
52 and 53 week
X : A~Z : Internal Code

Part Number	Package	Identification Code
AP2501AFGE-7	U-DFN3030-8	5W
AP2511AFGE-7	U-DFN3030-8	5X

(5) U-DFN2020-6

(Top View)



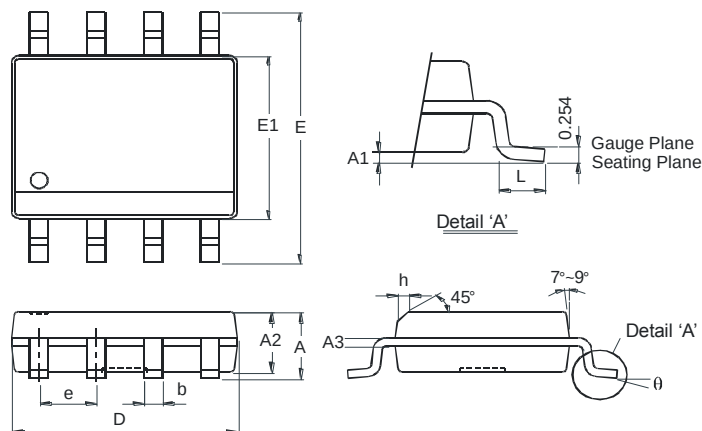
XX : Identification Code
Y : Year : 0~9
W : Week : A~Z : 1~26 week;
a~z : 27~52 week; z represents
52 and 53 week
X : A~Z : Internal Code

Part Number	Package	Identification Code
AP2501ASN-7	U-DFN2020-6	5Y
AP2511ASN-7	U-DFN2020-6	5Z

Package Outline Dimensions (All dimensions in mm.)

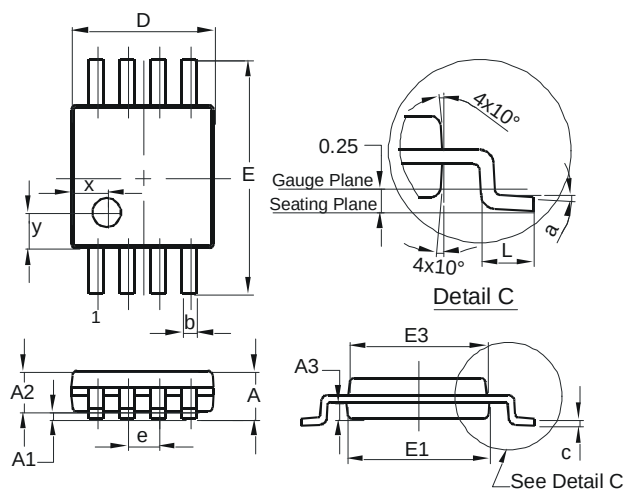
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.

1. Package type: SO-8



SO-8		
Dim	Min	Max
A	-	1.75
A1	0.10	0.20
A2	1.30	1.50
A3	0.15	0.25
b	0.3	0.5
D	4.85	4.95
E	5.90	6.10
E1	3.85	3.95
e	1.27 Typ	
h	-	0.35
L	0.62	0.82
θ	0°	8°
All Dimensions in mm		

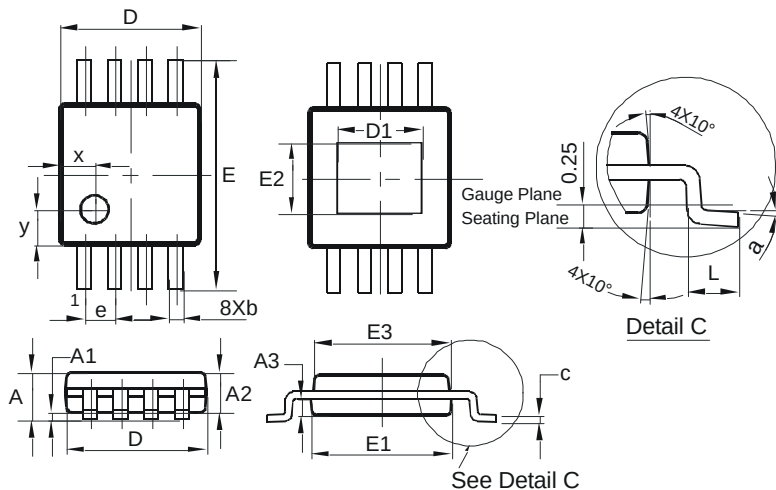
2. Package type: MSOP-8



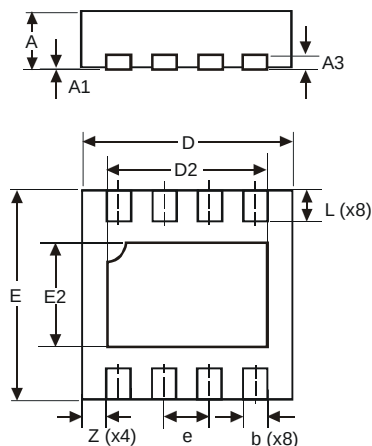
MSOP-8			
Dim	Min	Max	Typ
A	-	1.10	-
A1	0.05	0.15	0.10
A2	0.75	0.95	0.86
A3	0.29	0.49	0.39
b	0.22	0.38	0.30
c	0.08	0.23	0.15
D	2.90	3.10	3.00
E	4.70	5.10	4.90
E1	2.90	3.10	3.00
E3	2.85	3.05	2.95
e	-	-	0.65
L	0.40	0.80	0.60
a	0°	8°	4°
x	-	-	0.750
y	-	-	0.750
All Dimensions in mm			

Package Outline Dimensions (continued) (All dimensions in mm.)

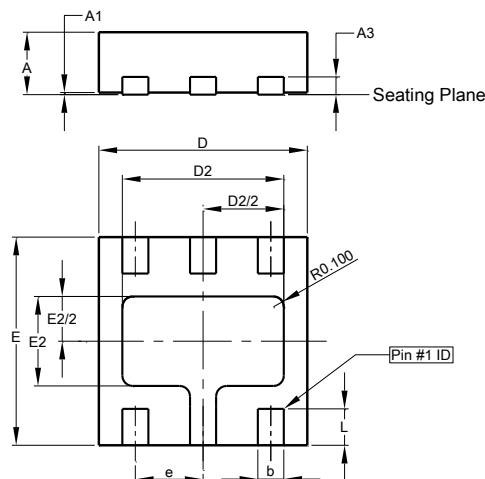
 Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.

3. Package type: MSOP-8EP


MSOP-8EP			
Dim	Min	Max	Typ
A	-	1.10	-
A1	0.05	0.15	0.10
A2	0.75	0.95	0.86
A3	0.29	0.49	0.39
b	0.22	0.38	0.30
c	0.08	0.23	0.15
D	2.90	3.10	3.00
D1	1.60	2.00	1.80
E	4.70	5.10	4.90
E1	2.90	3.10	3.00
E2	1.30	1.70	1.50
E3	2.85	3.05	2.95
e	-	-	0.65
L	0.40	0.80	0.60
a	0°	8°	4°
x	-	-	0.750
y	-	-	0.750
All Dimensions in mm			

4. Package type: U-DFN3030-8 Type E


U-DFN3030-8 Type E			
Dim	Min	Max	Typ
A	0.57	0.63	0.60
A1	0	0.05	0.02
A3	-	-	0.15
b	0.20	0.30	0.25
D	2.95	3.05	3.00
D2	2.15	2.35	2.25
E	2.95	3.05	3.00
e	-	-	0.65
E2	1.40	1.60	1.50
L	0.30	0.60	0.45
Z	-	-	0.40
All Dimensions in mm			

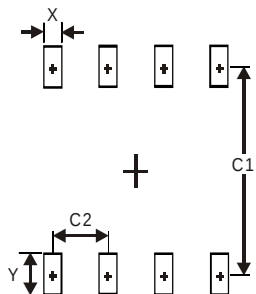
5. Package type: U-DFN2020-6


U-DFN2020-6			
Dim	Min	Max	Typ
A	0.57	0.63	0.60
A1	0	0.05	0.03
A3	—	—	0.15
b	0.20	0.30	0.25
D	1.95	2.075	2.00
D2	1.45	1.65	1.55
e	—	—	0.65
E	1.95	2.075	2.00
E2	0.76	0.96	0.86
L	0.30	0.40	0.35
All Dimensions in mm			

Suggested Pad Layout

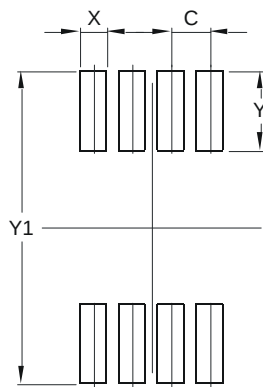
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

(1) Package type: SO-8



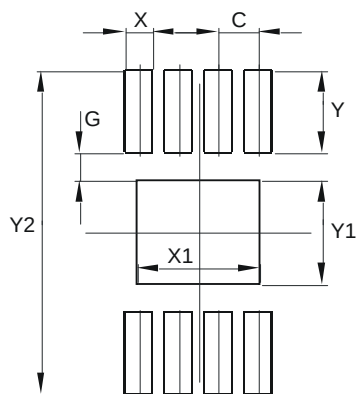
Dimensions	Value (in mm)
X	0.60
Y	1.55
C1	5.4
C2	1.27

(2) Package type: MSOP-8



Dimensions	Value (in mm)
C	0.650
X	0.450
Y	1.350
Y1	5.300

(3) Package type: MSOP-8EP

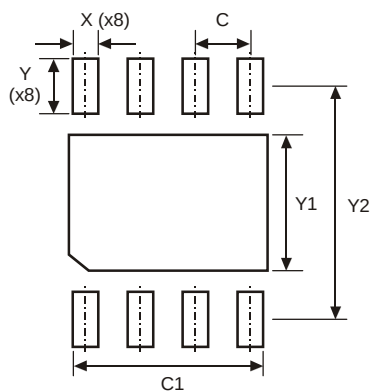


Dimensions	Value (in mm)
C	0.650
G	0.450
X	0.450
X1	2.000
Y	1.350
Y1	1.700
Y2	5.300

Suggested Pad Layout (continued)

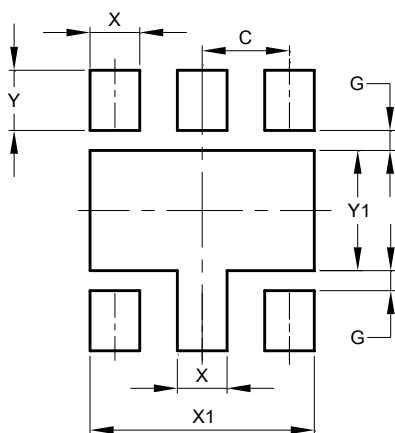
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

(4) Package type: U-DFN3030-8 Type E



Dimensions	Value (in mm)
C	0.65
C1	2.35
X	0.30
Y	0.65
Y1	1.60
Y2	2.75

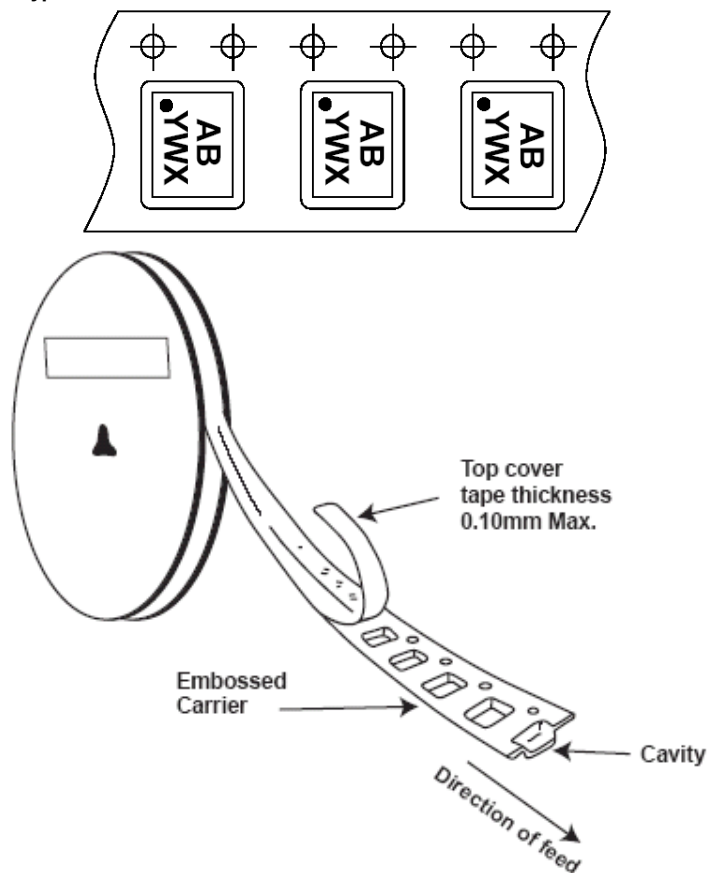
(5) Package type: U-DFN2020-6



Dimensions	Value (in mm)
C	0.65
G	0.15
X	0.37
X1	1.67
Y	0.45
Y1	0.90

Taping Orientation (Note 12)

For U-DFN2020-6 and U-DFN3030-8 Type E



Note: 12. The taping orientation of the other package type can be found on our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

www.diodes.com



**Стандарт
Электрон
Связь**

Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

Наши контакты:

Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург,
Промышленная ул, дом № 19, литера Н,
помещение 100-Н Офис 331